**Product data sheet** 

## 1. General description

NPN/PNP transistor pair in a SOT666 plastic package.

### 2. Features and benefits

- 300 mW total power dissipation
- Very small 1.6 mm x 1.2 mm ultra thin package
- · Excellent coplanarity due to straight leads
- Replaces two SC-75/SC-89 packaged transistors on same PCB area
- · Reduced required PCB area
- · Reduced pick and place costs.
- AEC-Q101 qualified

## 3. Applications

- · General purpose switching and amplification
- · Switch mode power supply complementary MOSFET driver
- · Complementary driver for audio amplifiers.

## 4. Quick reference data

### Table 1. Quick reference data

Symbol	Parameter	Conditions	l l	Min	Тур	Max	Unit
Per transist	tor; for the PNP transistor	with negative polarity				<u> </u>	
$V_{CEO}$	collector-emitter voltage	open base	-	-	-	45	V
I <sub>C</sub>	collector current		-	-	-	100	mA
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	•	-	200	mA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 2 mA	2	200	-	450	



## NPN/PNP general purpose transistor

# 5. Pinning information

### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1	6 5 4	C1 B2 E2
2	B1	base TR1		
3	C2	collector TR2		(TR1) TR2)
4	E2	emitter TR2		
5	B2	base TR2	1 2 3	E1 B1 C2
6	C1	collector TR1	SOT666	sym019

# 6. Ordering information

### **Table 3. Ordering information**

Type number	Package					
	Name	Description	Version			
BC847BVN		plastic, surface-mounted package; 6 leads; 0.5 mm pitch; 1.6 mm x 1.2 mm x 0.55 mm body	SOT666			

## 7. Marking

#### Table 4. Marking codes

Type number	Marking code
BC847BVN	13

## NPN/PNP general purpose transistor

# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit			
Per transistor;	Per transistor; for the PNP transistor with negative polarity								
V <sub>CBO</sub>	collector-base voltage	open emitter		-	50	V			
V <sub>CEO</sub>	collector-emitter voltage	open base		-	45	V			
V <sub>EBO</sub>	emitter-base voltage	open collector		-	5	V			
I <sub>C</sub>	collector current			-	100	mA			
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	200	mA			
I <sub>BM</sub>	peak base current			-	200	mA			
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	200	mW			
Tj	junction temperature			-	150	°C			
T <sub>amb</sub>	ambient temperature			-65	150	°C			
T <sub>stg</sub>	storage temperature			-65	150	°C			
Per device	•								
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	300	mW			

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

## 9. Thermal characteristics

#### **Table 6. Thermal characteristics**

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor	Per transistor						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	416	K/W

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

### NPN/PNP general purpose transistor

## 10. Characteristics

#### **Table 7. Characteristics**

 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transist	tor; for the PNP transistor v	with negative polarity				
I <sub>CBO</sub>	collector-base cut-off	V <sub>CB</sub> = 30 V; I <sub>E</sub> = 0 A	-	-	15	nA
	current	V <sub>CB</sub> = 30 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C	-	-	5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A	-	-	100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 2 mA	200	-	450	
V <sub>CEsat</sub>	collector-emitter	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 0.5 mA; T <sub>amb</sub> = 25 °C	-	-	100	mV
saturation vo	saturation voltage	$I_C$ = 100 mA; $I_B$ = 5 mA; Pulsed test: $t_p \le$ 300 µs; $\delta \le$ 0.02	-	-	300	mV
V <sub>BEsat</sub>	base-emitter saturation voltage	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 0.5 mA	-	755	-	mV
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 10 mA; f = 100 MHz	100	-	-	MHz
NPN transis	stor		'			
V <sub>BE</sub>	base-emitter voltage	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 2 mA	580	655	700	mV
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = 10 V; I <sub>E</sub> = 0 A; i <sub>e</sub> = 0 A; f = 1 MHz	-	-	1.5	pF
C <sub>e</sub>	emitter capacitance	$V_{EB} = 500 \text{ mV}; I_C = 0 \text{ A}; i_c = 0 \text{ A};$ f = 1 MHz	-	11	-	pF
PNP transis	stor		'			
V <sub>BE</sub>	base-emitter voltage	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -2 mA	-600	-655	-750	mV
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = -10 V; I <sub>E</sub> = 0 A; i <sub>e</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C	-	-	2.2	pF
C <sub>e</sub>	emitter capacitance	$V_{EB}$ = -500 mV; $I_{C}$ = 0 A; $i_{c}$ = 0 A; $f$ = 1 MHz	-	10	-	pF

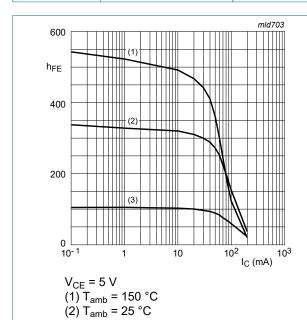


Fig. 1. NPN TR1: DC current gain as a function of collector current; typical values

(3)  $T_{amb} = -55 \, ^{\circ}C$ 

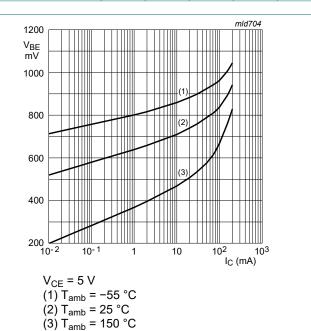
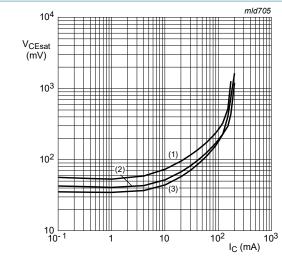


Fig. 2. NPN TR1: Base-emitter voltage as a function of collector current; typical values

#### NPN/PNP general purpose transistor



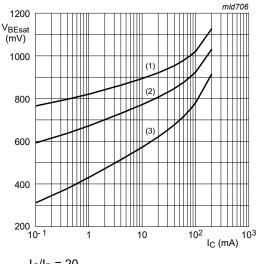
$$I_C/I_B = 20$$

$$(1) T_{amb} = 150^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(1) T<sub>amb</sub> = 150°C (2) T<sub>amb</sub> = 25 °C (3) T<sub>amb</sub> = -55 °C

Fig. 3. **NPN TR1: Collector-emitter saturation voltage** as a function of collector current; typical values



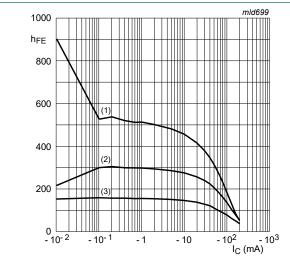
$$I_{\rm C}/I_{\rm B} = 20$$

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

 $I_{C}/I_{B} = 20$ (1)  $T_{amb} = -55 \,^{\circ}C$ (2)  $T_{amb} = 25 \,^{\circ}C$ (3)  $T_{amb} = 150 \,^{\circ}C$ 

NPN TR1: Base-emitter saturation voltage as a Fig. 4. function of collector current; typical values



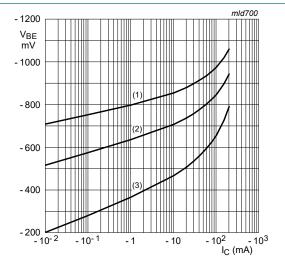
$$V_{CE}$$
 = -5  $V$ 

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3)  $T_{amb} = -55 \, ^{\circ}C$ 

PNP TR2: DC current gain as a function of Fig. 5. collector current; typical values



$$V_{CE} = -5 V$$

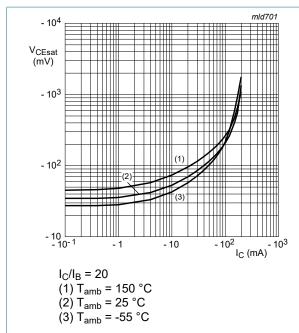
$$(1) T_{amb} = -55 °C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

PNP TR2: Base-emitter voltage as a function of Fig. 6. collector current; typical values

#### NPN/PNP general purpose transistor



**PNP TR2: Collector-emitter saturation voltage** Fig. 7. as a function of collector current; typical values

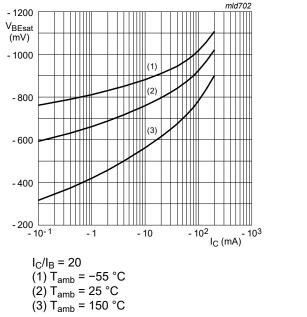


Fig. 8. PNP TR2: Base-emitter saturation voltage as a function of collector current; typical values

## 11. Test information

### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

## NPN/PNP general purpose transistor

# 12. Package outline

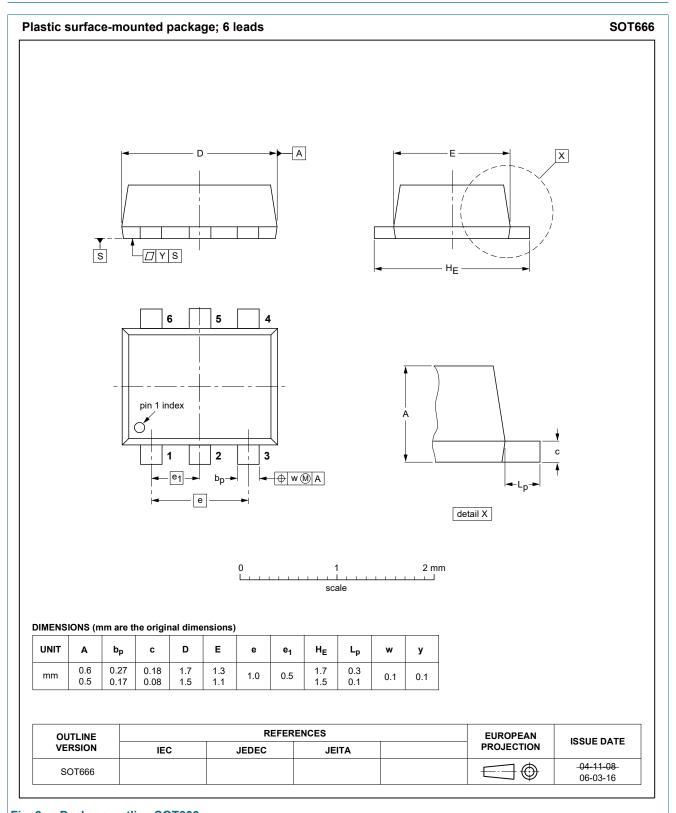
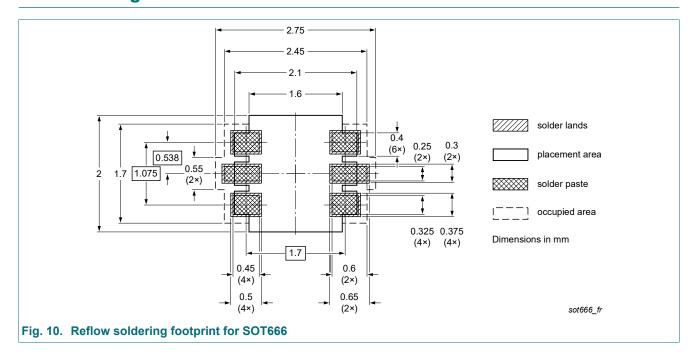


Fig. 9. Package outline SOT666

### NPN/PNP general purpose transistor

# 13. Soldering



## NPN/PNP general purpose transistor

# 14. Revision history

#### **Table 8. Revision history**

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Data sheet ID	Release date	Data sheet status	Change notice	Supersedes				
BC847BVN v.3	20190520	Product data sheet	-	BC847BVN v.2				
Modifications:	Nexperia.	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>						
BC847BVN v.2	20011107	Product data sheet	-	BC847BVN v.1				
BC847BVN v.1	20010830	Product data sheet	-	-				

### NPN/PNP general purpose transistor

## 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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BC847BVN

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